NSN 5962-01-159-3854

Memory Microcircuit - Page 1 of 1



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Body Length:

Between 0.880 inches and 0.920 inches

Body Width:

Between 0.265 inches and 0.310 inches

Body Height:

Between 0.140 inches and 0.165 inches

Maximum Power Dissipation Rating:

1.2 watts

Operating Tempurature Range:

+0.0/+70.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Hermetically sealed and high performance and 3-state output and high speed

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Metal oxide-semiconductor logic

Input Circuit Pattern:

15 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

7.0 volts power source

Time Rating Per Chacteristic:

45.00 nanoseconds propagation delay time, low to high level output

Memory Device Type:

Ram

Memory Capacity:

Unknown

Terminal Type And Quantity:

18 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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